





### C Series High Voltage Application

Type:

C4520 [EIA CC1808] C4532 [EIA CC1812]

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### REMINDERS

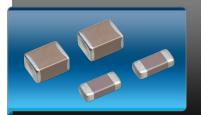
Please read before using this product

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# MULTILAYER CERAMIC CHIP CAPACITORS



**⊗TDK** 

# C Series High Voltage Application

### **Features**



- Advanced design provides improved withstand voltage characteristics.
  - TDK's proprietary internal electrode structure and the use of low-dielectric-strength material result in highly reliable performance in high-voltage applications.
  - Complies with ISO8802-3 for LAN applications.
  - Designed exclusively for reflow soldering.



- This product intended solely for reflow soldering.
- A slit of about 1mm on the circuit board is recommended to improve removal of the flux after soldering.
- Ensure that this product is completely dried following washing.
- Because this product will be subjected to high voltages, use only low-activity rosin flux (with 0.2% max. of chlorine).
- Using this product with aluminum circuit boards must be considered a special implementation because the high heat stress levels are involved. In case of using aluminum circuit boards, please contact TDK.

### Part Number Construction

Series Name						nternal Codes	
Dimensions L x	: W (mm) ——				— I	Packaging Style	
Case Code	Length	Width				Packaging Code	Style
C4520	4.50 ± 0.40	2.00 ± 0.30				Т	Tape & Reel
C4532	$4.50\pm0.40$	$\textbf{3.20} \pm \textbf{0.40}$			— (	Capacitance Toler	ance
Temperature Ch	naracteristic —					Tolerance Code	Tolerance
Temperature	Capacitance	Temperature				F	± 1pF
Characteristics	Change	Range				К	± 10%
COG	0±30 ppm/°C	-55 to +125°C				Jominal Canadita	200 (nE)
X7R	±15%	-55 to +125°C				Nominal Capacita	u ,
Datad Valtage (							s expressed in three
Rated Voltage (				-		•	units of pico Farads
Voltage Code	Voltage (DC)					(pF). The first and	d second digits identify
<u>3A</u>	1,000V					the first and second	nd significant figures of
3D	2,000V					the capacitance	The third digit identifies
3F	3,000V						lesignates a decimal
						point.	
						Capacitance Code	Capacitance
						0R5	0.5pF
						010	1pF
						102	1,000pF (1nF)

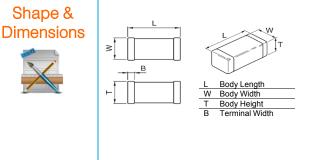
### Applications



 Inverter circuits with a liquid crystal backlight

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- LAN card
- General high voltage circuits.
- Noise bypass for power supply
- Transceiver for LAN
- Hub, etc.



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Dimensions in mm
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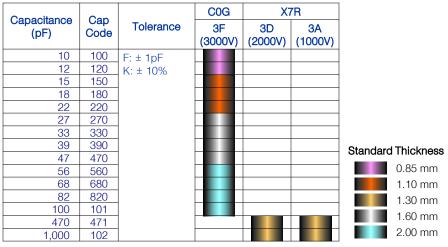
# MULTILAYER CERAMIC CHIP CAPACITORS



## C4520 [EIA CC1808]

#### Capacitance Range Chart

Temperature Characteristics: COG (0 ± 30ppm/<sup>o</sup>C), X7R (± 15%) Rated Voltage: 3,000 (3F), 2,000V (3D), 1,000V (3A)





### Capacitance Range Table

### C4520 [EIA CC1808]

#### Class 1 (Temperature Compensating)

Temperature Characteristics: COG (-55 to 125°C, 0±30 ppm/°C)

TDK Part Number (Ordering Code)	Temperature Characteristics	Rated Voltage	Capacitance (pF)	Capacitance Tolerance	Thickness (mm)
C4520C0G3F100F	C0G	3000V	10	± 1%	0.85 ± 0.10
C4520C0G3F120K	C0G	3000V	12	± 10%	0.85 ± 0.10
C4520C0G3F150K	C0G	3000V	15	± 10%	1.10 ± 0.15
C4520C0G3F180K	COG	3000V	18	± 10%	1.10 ± 0.15
C4520C0G3F220K	C0G	3000V	22	± 10%	1.10 ± 0.15
C4520C0G3F270K	COG	3000V	27	± 10%	1.60 ± 0.20
C4520C0G3F330K	C0G	3000V	33	± 10%	1.60 ± 0.20
C4520C0G3F390K	C0G	3000V	39	± 10%	1.60 ± 0.20
C4520C0G3F470K	COG	3000V	47	± 10%	1.60 ± 0.20
C4520C0G3F560K	C0G	3000V	56	± 10%	$2.00 \pm 0.20$
C4520C0G3F680K	C0G	3000V	68	± 10%	2.00 ± 0.20
C4520C0G3F820K	COG	3000V	82	± 10%	2.00 ± 0.20
C4520C0G3F101K	C0G	3000V	100	± 10%	2.00 ± 0.20

#### Class 2 (Temperature Stable)

Temperature Characteristics: X7R (-55 to +125°C, ±15%)

TDK Part Number (Ordering Code)	Temperature Characteristics	Rated Voltage	Capacitance (pF)	Capacitance Tolerance	Thickness (mm)
C4520X7R3A471K	X7R	1000V	470	± 10%	1.30 ± 0.15
C4520X7R3A102K	X7R	1000V	1,000	± 10%	1.30 ± 0.15
C4520X7R3D471K	X7R	2000V	470	± 10%	1.30 ± 0.15
C4520X7R3D102K	X7R	2000V	1,000	± 10%	1.30 ± 0.15

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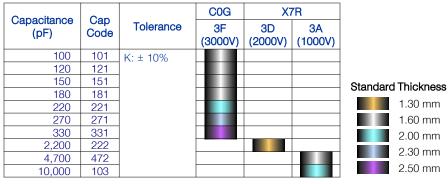
# MULTILAYER CERAMIC CHIP CAPACITORS



## C4532 [EIA CC1812]

#### Capacitance Range Chart

Temperature Characteristics: COG (0 ± 30ppm/<sup>o</sup>C), X7R (± 15%) Rated Voltage: 3,000 (3F), 2,000V (3D), 1,000V (3A)





Capacitance Range Table

## C4532 [EIA CC1812]

#### Class 1 (Temperature Compensating)

Temperature Characteristics: COG (-55 to 125°C, 0±30 ppm/°C)

TDK Part Number (Ordering Code)	Temperature Characteristics	Rated Voltage	Capacitance (pF)	Capacitance Tolerance	Thickness (mm)
C4532C0G3F101K	COG	3000V	100	± 10%	1.60 ± 0.30
C4532C0G3F121K	COG	3000V	120	± 10%	$1.60 \pm 0.30$
C4532C0G3F151K	COG	3000V	150	± 10%	$1.60 \pm 0.30$
C4532C0G3F181K	COG	3000V	180	± 10%	$1.60 \pm 0.30$
C4532C0G3F221K	COG	3000V	220	± 10%	$2.00 \pm 0.20$
C4532C0G3F271K	COG	3000V	270	± 10%	$2.30 \pm 0.20$
C4532C0G3F331K	COG	3000V	330	± 10%	$2.50 \pm 0.30$

#### Class 2 (Temperature Stable)

Temperature Characteristics: X7R (-55 to +125°C, ±15%)

TDK Part Number (Ordering Code)	Temperature Characteristics	Rated Voltage	Capacitance (pF)	Capacitance Tolerance	Thickness (mm)
C4532X7R3A472K	X7R	1000V	4,700	± 10%	1.60 ± 0.30
C4532X7R3A103K	X7R	1000V	10,000	± 10%	2.00 ± 0.20
C4532X7R3D222K	X7R	2000V	2,200	± 10%	1.30 ± 0.15

# MULTILAYER CERAMIC CHIP CAPACITORS



### General Specifications

## C Series – High Voltage Application

No.	ltem	Perfor	mance		Test or Inspection Method		
1	External Appearance	No defe perform	ects which mance.	ay affect	Inspect with magnifying glass (3 $ imes$ ).		
2	Insulation Resistance	10,000	MΩ min.		Apply 500	V DC for 60s.	
3	Voltage Proof		nd test voltag on breakdow	ge without n or other damage.			shall be applied for 1 to 5s. ht shall not exceed 50mA.
4	Capacitance	Within t	he specified	tolerance.	Class	Measuring Frequency	Measuring Voltage
					Class 1	1MHz±10%	0.5 - 5 V <sub>rms</sub>
					Class 2	1kHz±10%	1.0±0.2V <sub>rms</sub>
5	Q (Class 1)	Rated CapacitanceQ30pF and over1,000 min.Under 30pF400+20 × C min.C : Rated capacitance (pF)			See No.4	in this table for	measuring condition.
6	Dissipation Factor (Class 2)	T.C.     D.F.       X7R     0.03 max.			See No.4 in this table for measuring condition.		
7	Temperature Characteristics of Capacitance (Class 1)	•			Temperature coefficient shall be calculated based on values at 25°C and 85°C temperature. Measuring temperature below 20°C shall be -10°C and -25°C.		
8	Temperature Characteristics of Capacitance (Class 2)	Capacitance Change (%)   No Voltage Applied   X7R: ± 15%			the followi for each s	ng table after th	<b>C)</b> . ± 2 emp. ± 2 . ± 2
9	Robustness of Terminations	No sign of termination coming off, breakage of ceramic, or other abnormal signs.					ors on P.C. board (shown in bushing force of 5N with Pushing force P.C. board

General Specifications

## MULTILAYER CERAMIC CHIP CAPACITORS



## C Series – High Voltage Application

No.	ltem	Performance				Test or Inspection Method			
10	Solderability		New solder to cover over 75% of termination.			•	tely soak both terminations $^{2}$ C for 2 $\pm$ 0.5s.	in solder at	
		25% ma	y have p	oin ho	oles or rough spots	Solder: H63A (JIS Z 3282)			
		but not c	oncentr	ated	in one spot.	Flux: Is	Flux: Isopropyl alcohol (JIS K 8839)		
		not be e	xposed	due t	A sections" shall o melting or n material.	R	osin (JIS K 5902) 25% soli	d solution.	
		É		A se	ction				
11	Vibration						tely soak both terminations	in solder at	
	External	No mech	nanical c	lama	ge.		$^{\circ}$ C for 5±1s.		
	appearance						ing condition		
	Capacitance	Charac	teristics		ange from the		emp.: 150±10°C me: 1 to 2min.		
		Class 1	COG	-	Lue before test       2.5 %			N .	
		Class 1 Class 2	X7R	_	7.5 %	Flux: Isopropyl alcohol (JIS K 8839) Rosin (JIS K 5902) 25% solid solution.			
						-			
	Q (Class 1)	Rated Capacitance		Q	Solder:	H63A (JIS Z 3282)			
		-	30pF and over Under 30pF		1,000 min. 400+20×C min.		Leave the capacitor in ambient conditions for 6 to 2 (Class 1) as $24 \pm 2b$ (Class 2) before measurement		
						(Class 1) or 24±2h (Class 2) before measurement			
			C : Rated capacitance (pF)						
	D.F. (Class 2)	Meet the	e initial s	pec.					
12	Temperature cycle	)	No mechanical damage.			Reflow solder the capacitor on P.C. board (shown			
	External appearance	No mech				in Appendix 1) before testing. Expose the capacitor in the conditions step1			
	Capacitance	Characte	eristics		ange from the ue before test	•	n step 4 and repeat 5 tim the capacitor in ambient	5	
		Class 1	C0G	-	.5 %		ass 1) or 24 $\pm$ 2h (Class		
		Class 2	X7R	± 7	7.5 %	measu	, , , ,	_,	
	Q (Class 1)	Rated C	apacitan	се	Q	Step	Temperature (°C)	Time (min.)	
		30pF and	d over		1,000 min.	1	Min. operating temp. $\pm 3$	30 ± 3	
		Under 30	DpF		400+20×C min.	2	Reference Temp.	2-5	
			C : Rate		ated capacitance (pF)	3	Max. operating temp. $\pm$ 2	30 ± 2	
	D.F. (Class 2)	Meet the	e initial s	pec.		4	Reference Temp.	2 - 5	
	Insulation Resistance	Meet the initial spec.				-			
	VoltageNo insulation breakdown or otherProofdamage.		-						

## MULTILAYER CERAMIC CHIP CAPACITORS



### General Specifications

## C Series – High Voltage Application

No.	ltem	Performa	ance		Test or Inspection Method	
13	Moisture Resist				Reflow solder the capacitors on P.C. board (shown in Appendix 1) before testing.	
	External appearance	No mechanical damage.			Leave at temperature $40\pm2^{\circ}$ C, 90 to 95%RH for 500 +24,0h.	
	Capacitance	Character	istics	Change from the value before test	Leave the capacitors in ambient conditions for 6 to 24	
		Class 1	C0G	±5 %	(Class 1) or 24 $\pm$ 2h (Class 2) before measurement.	
		Class 2	X7R	±12.5 %	_	
	Q (Class 1)	Rated Cap	acitance	Q		
		30pF and o	over	350 min.		
		10pF and o under 30pF		275+5/2×C min.		
		C : Rated capacitance (pF)				
	D.F. (Class 2)	Character X7R: 200%		al spec. max.	-	
	Insulation Resistance	1,000MΩ I	min.		-	
14	Life				Reflow solder the capacitors on P.C. board (shown in Appendix 1) before testing.	
	External appearance	No mecha	nical dar	nage.	Apply rated voltage at maximum operating temperature $\pm 2^{\circ}$ C for 1,000 +48, 0h.	
	Capacitance	Characteristics Change from the value before test			Charge/discharge current shall not exceed 50mA.	
		Class 1	C0G	±3 %	Leave the capacitor in ambient conditions for 6 to 24h	
		Class 2	X7R	±15 %	(Class1) or 24±2h (Class2) before measurement.	
	Q (Class 1)	Rated Cap	acitanco	Q	Voltage conditioning:	
		30pF and c		350 min.	Voltage treat the capacitors under testing temperature and voltage for 1 hour.	
		10pF and over to under 30pF		275+5/2×C min.	Leave the capacitors in ambient conditions for $24\pm 2h$	
			C : Ra	ated capacitance (pF)	before measurement.	
	D.F. (Class 2)	D.F. (Class 2) Characteristics			Use this measurement for initial value.	
	X7R: 200% of initial spec		al spec. max.			
	Insulation Resistance	1,000MΩ min.			-	

\*As for the initial measurement of capacitors (Class 2) on number 8, 11, 12 and 13, leave capacitors at 150 –10, 0°C for 1 hour and measure the value after leaving capacitor for 24±2h in ambient condition.

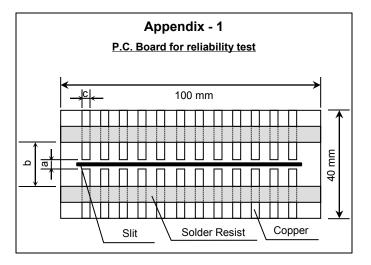
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## MULTILAYER CERAMIC CHIP CAPACITORS



General Specifications

## C Series – High Voltage Application



Material : Glass Epoxy (As per JIS C6484 GE4)

P.C. Board thickness: 1.6mm

Copper (thickness 0.035mm)
Solder resist

Case Code Dimensions (mm)

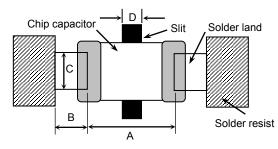
Case	Coue	Dimensions (mm)				
JIS	EIA	а	b	С		
C4520	CC1808	3.5	7.0	2.5		
C4532	CC1812	3.5	7.0	3.7		

# MULTILAYER CERAMIC CHIP CAPACITORS



### C Series – High Voltage Application

#### Recommended Soldering Land Pattern



· This product intended solely for reflow soldering.

• A slit of about 1mm on the circuit board is recommended to improve removal of the flux after soldering.

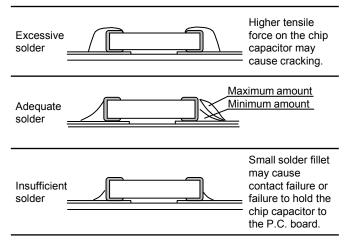
• Ensure that this product is completely dried following washing.

• Because this product will be subjected to high voltages, use only low-activity rosin flux (with 0.2% max. of chlorine).

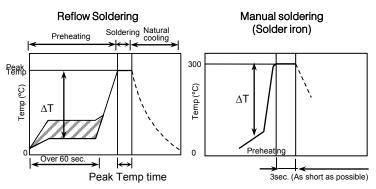
• Using this product with aluminum circuit boards must be considered a special implementation because the high heat stress levels are involved. In case of using aluminum circuit boards, please contact TDK.

<b>Reflow Solde</b>	Unit: mm		
Туре	C4520	C4532 [CC1812]	
Symbol	[CC1808]		
A	3.1 – 3.7	3.1 – 3.7	
В	1.2 – 1.4	1.2 – 1.4	
С	1.5 – 2.0	2.4 – 3.2	
D	1.0 – 1.3	1.0 – 1.3	

#### Recommended Solder Amount



#### Recommended Soldering Profile



#### **Recommended soldering duration**

Temp./	Reflow S	oldering	
Dura. Solder	Peak temp (°C)	Duration (sec.)	
Sn-Pb Solder	230 max.	20 max.	
Lead-Free Solder	260 max.	10 max.	

Recommended solder compositions Sn-37Pb (Sn-Pb solder) Sn-3.0Ag-0.5Cu (Lead Free Solder)

#### Preheating Condition

Soldering	Temp. (°C)
Reflow soldering	∆T ≤ 130
Manual soldering	∆T ≤ 130

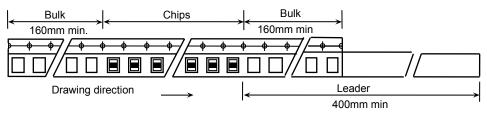
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# MULTILAYER CERAMIC CHIP CAPACITORS

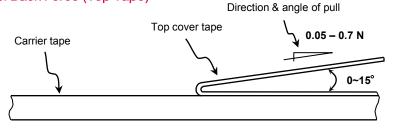


## C Series – High Voltage Application

#### Carrier Tape Configuration



### • Peel Back Force (Top Tape)



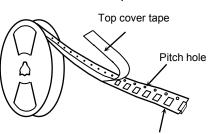
• Carrier tape shall be flexible enough to be wound around a minimum radius of 30mm with components in tape.

 $\bullet$  The missing of components shall be less than 0.1%

• Components shall not stick to the cover tape.

• The cover tape shall not protrude beyond the edges of the carrier tape not shall cover the sprocket holes.

#### Chip Quantity Per Reel and Structure of Reel



Plastic Carrier Tape & Reel

Plastic carrier tape

Case Code		Ohim	<b>T</b>	Chip quantity (pcs.)		
JIS	EIA	Chip Thickness	Taping Material	φ178mm (7") reel	Ф330mm (13") reel	
C4520 CC1808	0.85 mm					
		1.10 mm			5,000	
	1.30 mm	Plastic	1,000			
	1.60 mm			3,000		
	2.00 mm					
C4532 CC1812	1.30 mm			5,000		
		1.60 mm		1,000	- 3,000	
	CC1812	2.00 mm	Plastic			
		2.30 mm		500		
		3.20 mm		500		

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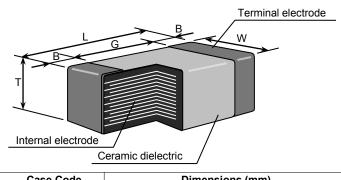
## MULTILAYER CERAMIC CHIP CAPACITORS



## C Series – High Voltage Application

Inside Structure & Material System

Shape & Dimensions



Case Code		Dimensions (mm)				
JIS	EIA	L	w	Т	В	G
				0.85 mm	0.30 min	
				1.10 mm	0.30 min	
C4520	CC1808	4.50	2.00	1.30 mm	2.00 min	2.00 min
				1.60 mm	0.30 min	
				2.00 mm	0.30 11111	
				1.30 mm	0.30 min.	
				1.60 mm		
C4532	CC1812	4.50	3.20	2.00 mm	0.20 min	2.00 min
				2.30 mm		
				3.20 mm	0.30 min.	

#### Environmental Information

TDK Corporation established internal product environmental assurance standards that include the six hazardous substances banned by the EU RoHS Directive<sup>1</sup> enforced on July 1, 2006 along with additional substances independently banned by TDK and has successfully completed making general purpose electronic components conform to the RoHS Directive<sup>2</sup>.

- Abbreviation for Restriction on Hazardous Substances, which refers to the regulation EU Directive 2002/95/EC on hazardous substances by the European Union (EU) effective from July 1, 2006. The Directive bans the use of six specific hazardous substances in electric and electronic devices and products handled within the EU. The six substances are lead, mercury, cadmium, hexavalent chromium, PBB (polybrominated biphenyls), and PBDE (polybrominated diphenyl ethers).
- This means that, in conformity with the EU Directive 2002/95/EC, lead, cadmium, mercury, hexavalent chromium, and specific bromine-based flame retardants, PBB and PBDE, have not been used, except for exempted applications.
- For REACH (SVHC : 15 substances according to ECHA / October 2008) : All TDK MLCC do not contain these 15 substances.
- For European Directive 2000/53/CE and 2005/673/CE : Cadmium, Hexavalent Chromium, Mercury, Lead are not contained in all TDK MLCC.
- For European Directive 2003/11/CE : Pentabromodiphenyl-ether, Octabromodiphenyl-ether are not contained in all TDK MLCC.

No.	NAME	MATERIAL	
		Class 1	Class 2
(1)	Ceramic Dielectric	CaZrO <sub>3</sub>	BaTiO <sub>3</sub>
(2)	Internal Electrode	Nickel (Ni)	
(3)		Copper (Cu)	
(4)	Termination	Nickel (Ni)	
(5)		Tin (Sn)	